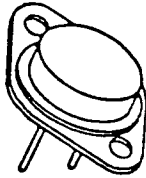


X00135

SFT6925A NPN HIGH VOLTAGE HIGH SPEED POWER TRANSISTOR 60 AMPS, 1000V	SSDI
	14849 FIRESTONE BLVD. LA MIRADA, CA. 90638 (213) 921-9660 FAX (213) 921-2396

CASE STYLE
JEDEC TO-3 WITH .060 PINS

FEATURES



- ▶ VERY FAST SWITCHING SPEED (100KHz)
- ▶ HIGH VOLTAGE (1000V)
- ▶ LOW VCE (SAT) AT IC = 20A
- ▶ HIGH CURRENT REPLACEMENT FOR: 2N6678, 2N6921A, 2N6923A, 2N6924A, 2N6925A, MJ16018
- ▶ EXTENDED RBSOA & FBSOA (see Fig. 1&2)
- ▶ RUGGEDNESS TO SWITCH UP TO 60AMPS @ 500V @ RBSOA

MAXIMUM RATINGS

RATING	SYMBOL	VALUE	UNIT
Collector-Emitter Voltage	VCEO	450	Volts
Collector-Base Voltage	VCBO	1000	Volts
Emitter-Base Voltage	VEBO	9	Volts
Collector Current	IC	60	Amps
Base Current	IB	6	Amps
Total Device Dissipation @ Tc = 25 °C Derate Above 25 °C	PD	175 1	Watts W/ °C
Operating and Storage Temperature	TJ, Tstg	-65 to +200	°C

THERMAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	VALUE	UNIT
Thermal Resistance, Junction to Case	RθJC	0.63	°C/W

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage* (IC = 200mAdc)	BVCEO	450		Volts
Collector-Base Breakdown Voltage (IC = 200uAdc)	BVCBO	1000		Volts

Rev. 6/89 B227E

Note: Specifications subject to change without notice.

ELECTRICAL CHARACTERISTICS

Characteristics		Symbol	Min	Max	Unit
Emitter-Base Breakdown Voltage ($I_E = 500 \mu A$)		BVEBO	9	-	Vdc
Collector Cutoff Current ($V_{CE} = 85V_{dc}$)		ICBO	-	1	μA
Emitter Cutoff Current ($V_{EB} = 5V_{dc}$)		IEBO	-	0.1	μA
DC Current Gain* ($I_C = 5A$, $V_{CE} = 5V_{dc}$) ($I_C = 20A$, $V_{CE} = 5V_{dc}$) ($I_C = 30A$, $V_{CE} = 5V_{dc}$)		hFE	15 10 5	- - -	
Collector-Emitter Saturation Voltage* ($I_C = 10A$, $I_B = 1A$) ($I_C = 20A$, $I_B = 4A$)		VCE(SAT)	- -	0.8 1.0	Vdc
Base-Emitter Saturation Voltage* ($I_C = 10A$, $I_B = 1A$) ($I_C = 20A$, $I_B = 4A$)		VBE(SAT)	- -	1.0 1.2	Vdc
Current Gain Bandwidth Product ($I_C = 1A$, $V_{CE} = 10V_{dc}$, $f = 1MHz$)		fT	20	-	MHz
Output Capacitance ($V_{CB} = 10V_{dc}$, $I_E = 0A$, $f = 1MHz$)		Cob	-	500	pf
Delay Time	$I_C = 10A$ $I_{B1} = 1A$ $V_{BB} = -5V$ $R_{BB} = 0.6\Omega$ $LC = 0.25mH$ $V_{CLAMP} = 400V$	td	-	0.1	μs
Rise Time		tr	-	0.6	μs
Storage Time		ts	-	2.5	μs
Fall Time		tf	-	0.5	μs

*Pulse Test: Pulse Width = $300 \mu s$, Duty Cycle = 2%

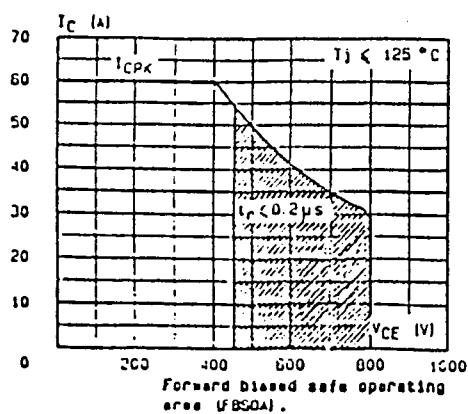


Figure 1

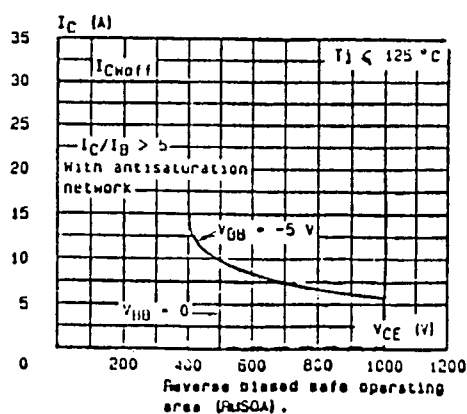


Figure 2

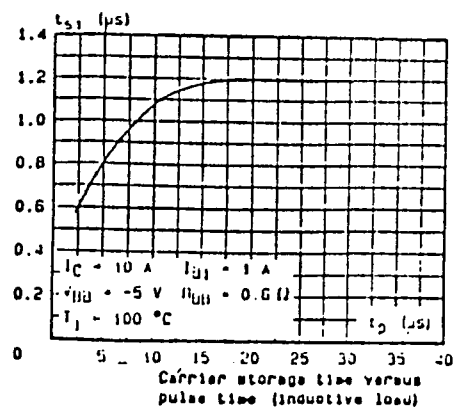


Figure 3

SSDI

SOLID STATE DEVICES, INC.

14849 FIRESTONE BOULEVARD, LA MIRADA, CA 90638
Telephone (213) 921-9660 ♦ FAX (213) 921-2396